OFE 13 TOTAL BUSINESS

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Shunpei YAMAZAKI et al.

Art Unit: 2813

Serial No.: 09/769,765

Examiner: Laura Schillinger

Filed

: January 26, 2001

Title : SEMIC

SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THERE

Commissioner for Patents Washington, D.C. 20231

## RESPONSE TO RESTRICTION/ELECTION REQUIREMENT

In response to the action mailed September 16, 2002, please amend the application as noted.

## In the claims:

Please cancel claims 1-16 and 25-47 without prejudice or disclaimer.

## Please amend claims 17-19 and 21 as follows:

17. (Amended) A semiconductor device comprising:

a first semiconductor layer and a segond semiconductor layer on an insulating surface;

a first insulating film on the first semiconductor layer and on the second semiconductor

a first electrode on the first insulating film, overlapping the first semiconductor layer;

a second electrode on the first insulating film, overlapping the second semiconductor

layer;

a source wiring on the first insulating film;

a second insulating film covering the first electrode and the source wiring;

a gate wiring on the second insulating film, connected to the first electrode;

a connection electrode on the second insulating film, connected to the source wiring and the first semiconductor layer; and

a pixel electrode on the second insulating film, connected to the first semiconductor

wherein at least one end of the pixel electrode overlays the source wiring with the second insulating film interposed therebetween.

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layer;

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